EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S29	174	("20010055852"|"20020030191"|"20020038891"|"20020047125"|"20020072247"|"20020102358"|"20040211980"|"20040212011"|"3629011"|"3924024"|"4466172"|"4811065"|"4875083"|"5111253"|"5170231"|"5170455"|"5184199"|"5270554"|"5348895"|"5384270"|"5385855"|"5393999"|"5396085"|"5479316"|"5506421"|"5510281"|"5510630"|"5587870"|"5629531"|"5710059"|"5726463"|"5734180"|"5739564"|"5763905"|"5804483"|"5814859"|"5837572"|"5851908"|"5877041"|"5877045"|"5885870"|"5917203"|"5939763"|"5960289"|"5972801"|"5976936"|"6020600"|"6025233"|"6025608"|"6028012"|"6048766"|"6054352"|"6063698"|"6096607"|"6100169"|"6107142"|"6117735"|"6133587"|"6136728"|"6165822"|"6180958"|"6190973"|"6204135"|"6204203"|"6211035"|"6221700"|"6228720"|"6238976"|"6239463"|"6246076"|"6297100"|"6297172"|"6303508"|"6316791"|"6344663"|"6399996"|"6420225"|"6429041"|"6448160"|"6455892"|"6551865"|"6573534"|"6593620"|"6610366"|"6653659"|"6759684").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/02 08:47
S30	2	"6956238".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/01 20:23
S31	2	09/911915	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/02 08:47
S32	5	"6239463".pn. "6096607".pn. "58148859".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/02 10:42
S33	19	("6239463").URPN.	USPAT	OR	OFF	2006/05/02 08:51
S34	4	("5072266" | "5801396" | "5821136" | "5985708").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/02 08:52
S35	13	("6096607").URPN.	USPAT	OR	OFF	2006/05/02 08:52

S36	4	("5072266" | "5801396" | "5821136" | "5985708").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/02 10:42
S37	146878	(silicon near2 carbide SiC)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:07
S38	267600	metal-oxide metal adj oxide	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:07
S39	0	firld near2 effect near2 transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/04 21:00
S40	128928	field near2 effect near2 transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:07
S41	174	("20010055852"|"20020030191"|"20020038891"|"20020047125"|"20020072247"|"20020102358"|"20040211980"|"20040212011"|"3629011"|"3924024"|"4466172"|"4811065"|"4875083"|"5111253"|"5170231"|"5170455"|"5184199"|"5270554"|"5348895"|"5384270"|"5385855"|"5393999"|"5396085"|"5479316"|"5506421"|"5510281"|"5510630"|"5587870"|"5629531"|"5710059"|"5726463"|"5734180"|"5739564"|"5763905"|"5804483"|"5814859"|"5837572"|"5851908"|"5877041"|"5877045"|"5885870"|"5917203"|"5939763"|"5960289"|"5972801"|"5976936"|"6020600"|"6025233"|"6025608"|"6028012"|"6048766"|"6054352"|"6063698"|"6096607"|"6100169"|"6107142"|"6117735"|"6133587"|"6136728"|"6165822"|"6180958"|"6190973"|"6204135"|"6204203"|"6211035"|"6221700"|"6228720"|"6238976"|"6239463"|"6246076"|"6297100"|"6297172"|"6303508"|"6316791"|"6344663"|"6399996"|"6420225"|"6429041"|"6448160"|"6455892"|"6551865"|"6573534"|"6593620"|"6610366"|"6653659"|"6759684").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/05 17:23

S42	2	("2002/0038891").URPN.	USPAT	OR	OFF	2006/05/04 21:05
S43	2	("6653659").URPN.	USPAT	OR	OFF	2006/05/04 21:07
S44	26	("3629011" | "5170231" | "5348895" | "5384270" | "5393999" | "5506421" | "5510281" | "5710059" | "5734180" | "5804483" | "5837572" | "5851908" | "5877041" | "5917203" | "5976936" | "6020600" | "6025233" | "6054352" | "6107142" | "6117735" | "6133587" | "6165822" | "6180958" | "6221700" | "6297100" | "6303508").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/04 21:07
S45	4	("6551865").URPN.	USPAT	OR	OFF	2006/05/04 21:33
S46	4	("5917203" | "6057558" | "6117735" | "6380565").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/04 21:34
S47	12	("5814859").URPN.	USPAT	OR	OFF	2006/05/04 21:40
S48	11	("4414560" | "4642674" | "5019522" | "5023678" | "5045900" | "5151762" | "5179034" | "5286981" | "5322802" | "5338945" | "5420450").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/04 21:41
S49	4479	S37 same S38	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/04 21:42
S50	25	S41 and S49	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/04 21:42
S51	39	S41 and S37 and S38	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/04 21:45
S52	0	S50 not S51	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/04 21:53
S53	1230	257/77,85.ccls.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/04 21:53
S54	3	257/21.054,e21.065.ccls.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/04 21:55
S55	66	257/e21.05,e21.051,e21.055.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/05 08:38

S56	566	257/e21.06,e21.19,e21.27,e21.62. ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/05 09:06
S57	146878	(silicon near2 carbide SiC)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/08 10:27
S58	267600	metal-oxide metal adj oxide	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:07
S59	128928	field near2 effect near2 transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:08
S61	2672	drift$3 near2 layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:11
S62	0	S56 with S61	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:11
S63	0	S56 same S61	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:11
S64	14	S56 and S61	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:10
S65	115125	drift$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:11
S66	0	S56 with S65	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:11

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S67	0	S56 same S65	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:12
S68	28	S56 and S65	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:12
S69	14	S68 not S64	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:13
S70	2015	S57 and S58 and S59	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:13
S71	88	S57 and S58 and S59 and S61	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 15:18
S72	107	257/e29.265,e29.32.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:23
S73	2	("6700156").URPN.	USPAT	OR	OFF	2006/05/05 09:43
S74	2	("20010026989" | "5883402").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/05/05 09:43
S75	1082	((S58 and S59) mosfet mesfet) and S61	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 15:16
S76	994	S75 not S71	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:49
S77	661	S76 and @ad<"20021220"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:58

EAST Search History

S78	6	10/183457	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 09:58
S79	2	"5814859".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 10:07
S80	5872	jfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 15:15
S81	267600	metal-oxide metal adj oxide	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 15:16
S82	128928	field near2 effect near2 transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 15:16
S83	2672	drift$3 near2 layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/08 10:28
S84	1118	((S81 and S82) mosfet mesfet jfet) and S83	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/07 18:46
S85	146878	(silicon near2 carbide SiC)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 15:17
S86	100	S85 and S81 and S84 and S83	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 15:17
S87	88	S85 and S81 and S82 and S83	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 15:18

S88	12	S86 not S87	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/05 15:18
S89	174	("20010055852"|"20020030191"|"20020038891"|"20020047125"|"20020072247"|"20020102358"|"20040211980"|"20040212011"|"3629011"|"3924024"|"4466172"|"4811065"|"4875083"|"5111253"|"5170231"|"5170455"|"5184199"|"5270554"|"5348895"|"5384270"|"5385855"|"5393999"|"5396085"|"5479316"|"5506421"|"5510281"|"5510630"|"5587870"|"5629531"|"5710059"|"5726463"|"5734180"|"5739564"|"5763905"|"5804483"|"5814859"|"5837572"|"5851908"|"5877041"|"5877045"|"5885870"|"5917203"|"5939763"|"5960289"|"5972801"|"5976936"|"6020600"|"6025233"|"6025608"|"6028012"|"6048766"|"6054352"|"6063698"|"6096607"|"6100169"|"6107142"|"6117735"|"6133587"|"6136728"|"6165822"|"6180958"|"6190973"|"6204135"|"6204203"|"6211035"|"6221700"|"6228720"|"6238976"|"6239463"|"6246076"|"6297100"|"6297172"|"6303508"|"6316791"|"6344663"|"6399996"|"6420225"|"6429041"|"6448160"|"6455892"|"6551865"|"6573534"|"6593620"|"6610366"|"6653659"|"6759684").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/05 17:24
S90	267654	metal-oxide metal adj oxide	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/07 18:47
S91	128958	field near2 effect near2 transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/07 18:47
S92	2673	drift$3 near2 layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/07 18:47

S93	273	((S90 and S91) mosfet mesfet jfet) and S92 and ((gate adj electrode) near5 polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/07 18:56
S94	215	((S90 and S91) mosfet mesfet jfet) and S92 and ((gate adj electrode) near3 polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/07 18:56
S95	94	((S90 and S91) mosfet mesfet jfet) and S92 and ((gate adj electrode) near polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/07 22:48
S96	83	S95 and source and drain	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/07 19:03
S97	2	"20020038891"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/07 21:00
S98	7	((S90 and S91) mosfet mesfet jfet) and S92 and ((gate adj contact) near polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/07 22:49
S99	717	((S90 and S91) mosfet mesfet jfet) and S92 and ((gate adj contact) near polysilicon metal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/07 22:49

S10 0	174	("20010055852"|"20020030191"|"2 0020038891"|"20020047125"|"2002 0072247"|"20020102358"|"2004021 1980"|"20040212011"|"3629011"|"3 924024"|"4466172"|"4811065"|"487 5083"|"5111253"|"5170231"|"51704 55"|"5184199"|"5270554"|"5348895 "|"5384270"|"5385855"|"5393999"| "5396085"|"5479316"|"5506421"|"5 510281"|"5510630"|"5587870"|"562 9531"|"5710059"|"5726463"|"57341 80"|"5739564"|"5763905"|"5804483 "|"5814859"|"5837572"|"5851908"| "5877041"|"5877045"|"5885870"|"5 917203"|"5939763"|"5960289"|"597 2801"|"5976936"|"6020600"|"60252 33"|"6025608"|"6028012"|"6048766 "|"6054352"|"6063698"|"6096607"| "6100169"|"6107142"|"6117735"|"6 133587"|"6136728"|"6165822"|"618 0958"|"6190973"|"6204135"|"62042 03"|"6211035"|"6221700"|"6228720 "|"6238976"|"6239463"|"6246076"| "6297100"|"6297172"|"6303508"|"6 316791"|"6344663"|"6399996"|"642 0225"|"6429041"|"6448160"|"64558 92"|"6551865"|"6573534"|"6593620 "|"6610366"|"6653659"|"6759684"). PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/08 09:04
S10 1	0	S100 and "6700156".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/08 09:04
S10 2	0	S100 and "6620697".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/08 09:05
S10 3	2	S100 and "5393999".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/08 09:05
S10 4	18539	257/57-61,66-72,368-401.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/05/08 10:26

S105	756	S104 and (silicon near2 carbide SiC)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/08 10:27
S106	28	S105 and drift$3 near2 layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/08 10:28